

System Lens Driver Series for Mobile Phone Cameras

Parallel Interface Type Lens Drivers for Voice Coil Motor



BD6883GUL.BH6453GUL.BD6886GUL.BD6369GUL

No.12015EAT02

Description

The BD6883GUL, and the BH6453GUL motor driver provide 1 Constant-Current Driver Half-bridge, and 1 Constant-Voltage Driver Half-bridge channel. The BD6886GUL, and the BD6369GUL motor driver provide 1 Constant-Voltage Driver H-bridge channel. These lens drivers are offered in an ultra-small functional lens system for use in an auto focus system using a Voice Coil motor.

Features

- 1) BD6883GUL Characteristics
 - 1) Ultra-small chip size package; 1.1mm × 1.6mm × 0.55mm
 - 2) Low ON-Resistance Power CMOS output; on high side PMOS typ. 0.65Ω , on low side NMOS typ. 0.40Ω
 - 3) ESD resistance (Human Body Model); 8kV
 - 4) Built-in ±5% high-precision Constant-Voltage Driver (phase compensation capacitor-free design)
 - 5) Built-in UVLO (Under Voltage Locked Out: UVLO)
 - 6) Built-in TSD (Thermal Shut Down) circuit
 - 7) Standby current consumption: 0µA Typ.

2) BH6453GUL Characteristics

- 1) Ultra-small chip size package; 1.5mm × 0.9mm × 0.55mm
- 2) Low ON-Resistance Power CMOS output; on high side PMOS typ.1.2 Ω , on low side NMOS typ.0.4 Ω
- 3) ESD resistance (Human Body Model); 8kV
- 4) Built in resistor for output current detect (phase compensation capacitor-free design)
- 5) 1.8V can be put into each control input terminal
- 6) Built-in UVLO (Under Voltage Locked Out: UVLO)
- 7) Built-in TSD (Thermal Shut Down) circuit
- 8) Standby current consumption: 0µA Typ.

3) BD6886GUL, BD6369GUL Characteristics

- 1) Ultra-small chip size package; 2.1mm × 2.1mm × 0.55mm
- 2) Low ON-Resistance Power CMOS output; on high and low sides in total typ. 0.80Ω
- 3) ESD resistance (Human Body Model); 8kV
- 4) Built-in ±5% high-precision Constant-Voltage Driver (phase compensation capacitor-free design)
- 5) Control Input mode selection function
- 6) Built-in UVLO (Under Voltage Locked Out: UVLO)
- 7) Built-in TSD (Thermal Shut Down) circuit
- 8) Standby current consumption: 0µA Typ.

■Absolute Maximum Ratings (Ta=+25°C)

3 (/					
Parameter	Symb		Lir	nit		Unit
Parameter	ol	BD6883GUL	BH6453GUL	BD6886GUL	BD6369GUL	Offic
Power supply voltage	VCC	-0.5 to +6.5	-0.5 to +4.5	-0.5 to +6.5	-0.5 to +6.5	V
Motor power supply voltage	VM	-	-	-0.5 to +6.5	-0.5 to +6.5	V
Control input voltage	VIN	-0.5 to VCC+0.5	-0.5 to VCC+0.5	-0.5 to VCC+0.5	-0.5 to VCC+0.5	V
Input voltage for Constant-Voltage setting	VLIM	-0.5 to VCC+0.5	-	-0.5 to VM+0.5	-0.5 to VM+0.5	V
Input voltage for Constant-Current setting	CLIM	-	-0.5 to VCC+0.5	-	•	V
Power dissipation	Pd	510 ^{**1}	430 ^{*2}	730 ^{**3}	730 ^{*3}	mW
Operating temperature range	Topr	-25 to +85	-25 to +85	-25 to +85	-25 to +85	°C
Junction temperature	Tjmax	+150	+125	+150	+150	°C
Storage temperature range	Tstg	-55 to +150	-55 to +125	-55 to +150	-55 to +150	°C
H-bridge output current	lout	-200 to +200 ^{**4}	-300 to +300 ^{**5}	-200 to +200 ^{**4}	-500 to +500 ^{**4}	mΑ

^{**1} Reduced by 4.08mW/°C over 25°C, when mounted on a glass epoxy board (50mm × 58mm × 1.75mm; 8 layers).

Operating Conditions

Develope	Curanh al		Lir	mit		Unit
Parameter	Symbol	BD6883GUL	BH6453GUL	BD6886GUL	BD6369GUL	
Power supply voltage	VCC	+2.5 to +5.5	+2.3 to +3.6	+2.5 to +5.5	+2.5 to +5.5	V
Motor power supply voltage	VM	-	-	+2.5 to +5.5	+2.5 to +5.5	V
Control input voltage	VIN	0 to VCC	0 to VCC	0 to VCC	0 to VCC	V
Input voltage for Constant-Voltage setting	VLIM	0 to VCC	-	0 to VM	0 to VM	V
Input voltage for Constant-Current setting	CLIM	-	0 to VCC	-	-	V
H-bridge output current	lout	-150 to +150 ^{*/6}	-200 to +200 ^{*/6}	-150 to +150 ^{*/6}	-400 +400 ^{*/6}	mA

^{*6} Must not exceed Pd or ASO.

●Power Dissipation Reduction

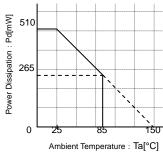


Fig.1 BD6883GUL Power Dissipation Reduction

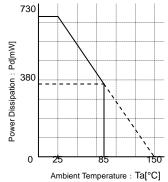


Fig.3 BD6886GUL Power Dissipation Reduction

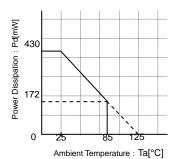


Fig.2 BH6453GUL Power Dissipation Reduction

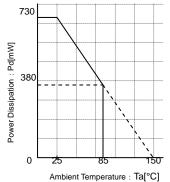


Fig.4 BD6369GUL Power Dissipation Reduction

 $^{^{**2}}$ Reduced by 4.30mW/°C over 25°C, when mounted on a glass epoxy board (50mm \times 58mm \times 1.75mm; 8 layers).

 $^{^{*3}}$ Reduced by 5.84mW/°C over 25°C, when mounted on a glass epoxy board (50mm \times 58mm \times 1.75mm; 8 layers).

^{**4} Must not exceed Pd, ASO, or Tjmax of 150°C.

^{**5} Must not exceed Pd, ASO, or Tjmax of 125°C.

Electrical Characteristics

1) BD6883GUL Electrical Characteristics (Unless otherwise specified, Ta=25°C, VCC=3.0V)

- DD0003GOL Electrical C			Limit		,	,
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Overall	I.					
Circuit current during standby operation	ICCST	-	0	10	μА	PS=0V
Circuit current	ICC	-	0.9	1.4	mA	PS=3V, VLIM=3V with no signal and load
Control input (VIN=IN, PS)						
High level input voltage	VINH	2.0	-	VCC	V	
Low level input voltage	VINL	0	-	0.7	V	
High level input current	IINH	15	30	60	μΑ	VINH=3V, pull-down resistor typ.100k Ω
Low level input current	IINL	-1	0	-	μA	VINL=0V
Input for Constant-Voltage se	etting					
Input current	IVLIM	-1.5	-0.5	-	μA	VLIM=0V
UVLO						
UVLO voltage	VUVLO	1.6	-	2.4	V	
Constant-Voltage Drive block	‹					
PMOS Output ON-Resistance	RONP	-	0.65	0.80	Ω	lo=-150mA
NMOS Output ON-Resistance	RONN	-	0.40	0.60	Ω	lo=+150mA
Output high-level voltage	VOH	1.9 × VLIM	2.0 × VLIM	2.1 × VLIM	V	VLIM=1V with 10Ω load
Output AC characteristic						
Turn-on time	ton	-	1.5	5	μs	lo=-150mA, 10Ω load
Turn-off time	toff	-	0.1	2	μs	lo=-150mA, 10Ω load
Rise time	tr	-	1.5	8	μs	lo=-150mA, 10Ω load
Fall time	tf	-	0.05	1	μs	lo=-150mA, 10Ω load

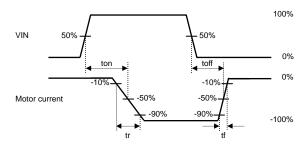


Fig.5 BD6883GUL I/O Switching Waveform (The direction flowing into IC is plus)

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2) BH6453GUL Electrical Characteristics (Unless otherwise specified, Ta=25°C, VCC=3.0V)

Davassatas	Comple ed		Limit		l lait	Conditions
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Overall						
Circuit current during standby operation	ICCST	-	0	5	μΑ	PS=0V
Circuit current	ICC	-	0.9	1.3	mA	PS=3V, IN=3V, no load
Control input (VIN=IN, PS)						
High-level input voltage	VINH	1.5	-	VCC	V	
Low-level input voltage	VINL	0	-	0.5	V	
High-level input current	IINH	15	30	60	μΑ	VINH=3V, pull down resistance typ.100kΩ
Low-level input current	IINL	-1	0	-	μA	VINL=0V
UVLO						
UVLO voltage	VUVLO	1.6	-	2.2	V	
Constant-Current Drive bloc	k					
PMOS Output ON-Resistance	RONP	-	1.2	1.5	Ω	lo=-200mA
NMOS Output ON-Resistance	RONN	-	0.35	0.50	Ω	Io=+200mA
Offset current	lofs	0	1	5	mA	CLIM=0V
Output current	lout	180	200	220	mA	CLIM=0.8V, RL=10Ω

Drive system of Constant-Current

$$I_{SINK}[A] = \frac{CLIM[V]}{2 \times 2.0(Typ.)[\Omega]}$$

I_{SINK}: VCC-OUT current
CLIM: VCC-OUT current setting voltage
R_{RNF}: VCC-OUT current detection resistance

3) BD6886GUL, BD6369GUL Electrical Characteristics (Unless otherwise specified, Ta=25°C, VCC=3.0V, VM=5.0V)

			Limit	•		Canditions
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Overall						
Circuit current during standby operation	ICCST	-	0	10	μΑ	PS=0V
Circuit current 1	ICC	-	0.9	1.4	mA	PS=3V, with no signal
Circuit current 2	IM	-	0.4	0.65	mA	PS=3V, VLIM=5V, no load
Control input (VIN=INA, INB	, SEL, PS)					
High-level input voltage	VINH	2.0	-	VCC	V	
Low-level input voltage	VINL	0	-	0.7	V	
High-level input current	IINH	15	30	60	μΑ	VINH=3V
Low-level input current	IINL	-1	0	-	μΑ	VINL=0V
Pull-down resistor	RIN	50	100	200	kΩ	
Input for Constant-Voltage se	etting					
Input current	IVLIM	-1.5	-0.5	-	μΑ	VLIM=0V
UVLO						
UVLO voltage	VUVLO	1.6	-	2.4	V	
Constant-Voltage Drive block	k					
Output ON-Resistance	RON	-	0.80	1.20	Ω	$lo=\pm 150 mA$ on high and low sides in total
Output high-level voltage	VOH	1.9 × VLIM	2.0 × VLIM	2.1 × VLIM	V	VLIM=1V with 10Ω load
Output AC characteristic						
Turn-on time	ton	-	1.5	5	μs	Io=±150mA with 10Ω load
Turn-off time	toff	-	0.1	2	μs	$lo=\pm 150mA$ with 10Ω load
Rise time	tr	-	2	8	μs	$lo=\pm 150mA$ with 10Ω load
Fall time	tf	-	0.05	1	μs	$lo=\pm 150$ mA with 10Ω load

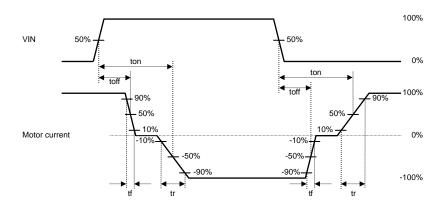


Fig.6 BD6886GUL, BD6369GUL I/O Switching Waveform

Electrical Characteristic Diagrams

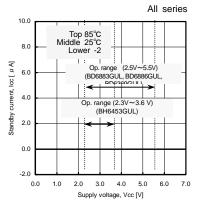


Fig.7 Standby Current (All series)

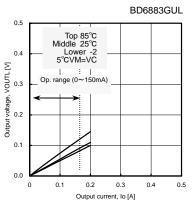


Fig.10 NMOS Output Voltage (BD6883GUL)

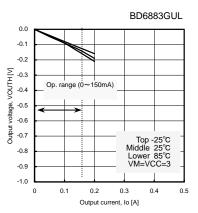


Fig.13 PMOS Output Voltage (BD6883GUL)

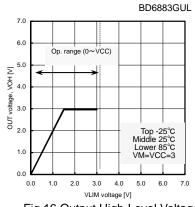


Fig.16 Output High-Level Voltage (BD6883GUL)

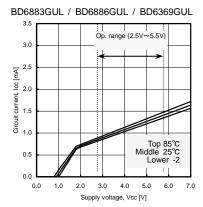


Fig.8 Circuit Current (BD6883GUL/BD6886GUL/BD6369GUL)

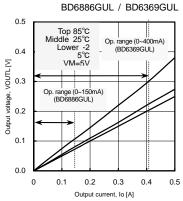


Fig.11 NMOS Output Voltage (BD6886GUL / BD6369GUL)

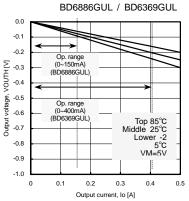


Fig.14 PMOS Output Voltage (BD6886GUL / BD6369GUL)

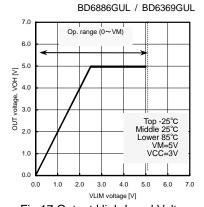


Fig.17 Output High-Level Voltage (BD6886GUL / BD6369GUL)

6/16

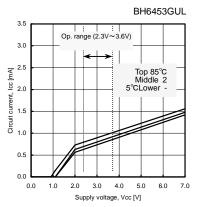


Fig.9 Circuit Current (BH6453GUL)

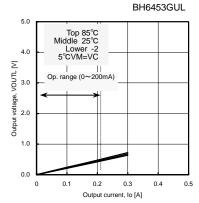


Fig.12 NMOS Output Voltage (BH6453GUL)

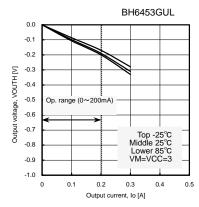


Fig.15 PMOS Output Voltage (BH6453GUL)

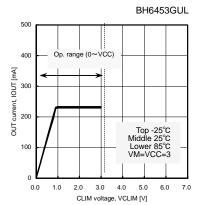


Fig.18 Current Limit Output Voltage (BH6453GUL)

- Block Diagram, Application Circuit Diagram, Pin Arrangement, Pin Function Table
 - 1) BD6883GUL Block Diagram, Application Circuit Diagram, Pin Arrangement, Pin Function Table

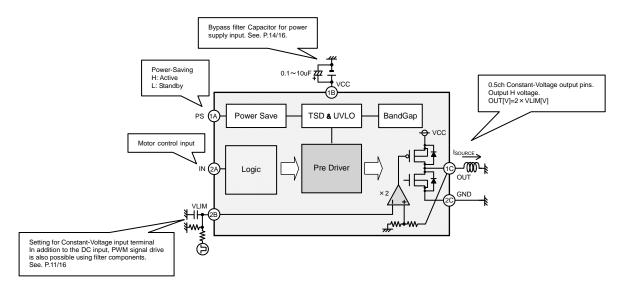


Fig.19 BD6883GUL Block Diagram, Application Circuit Diagram

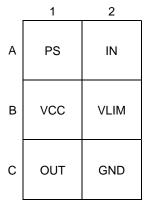


Fig.20 BD6883GUL Pin Arrangement (Top View)

BD6883GUL Pin Function Table

No.	Pin Name	Function		Pin Name	Function
1A	PS	Power-saving pin	2B	VLIM	Output high-level voltage setting pin
2A	IN	Control input pin	1C	OUT	Half-bridge output pin
1B	VCC	Power supply pin	2C	GND	Ground pin

2) BH6453GUL Block Diagram, Application Circuit Diagram, Pin Arrangement, Pin Function Table

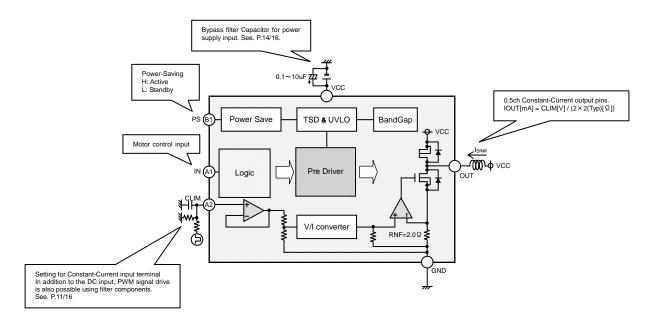


Fig.21 BH6453GUL Block Diagram, Application Circuit Diagram

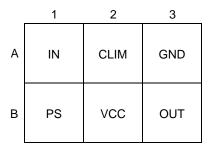


Fig.22 BH6453GUL Pin Arrangement (Top View)

BH6453GUL Pin Function Table

No.	Pin Name	Function		Pin Name	Function
1A	IN	Control input pin	1B	PS	Power-saving pin
2A	CLIM	Output current setting pin	2B	VCC	Power supply pin
3A	GND	Ground pin	3B	OUT	Half-bridge output pin

3) BD6886GUL, BD6369GUL Block Diagram, Application Circuit Diagram, Pin Arrangement, Pin Function Table

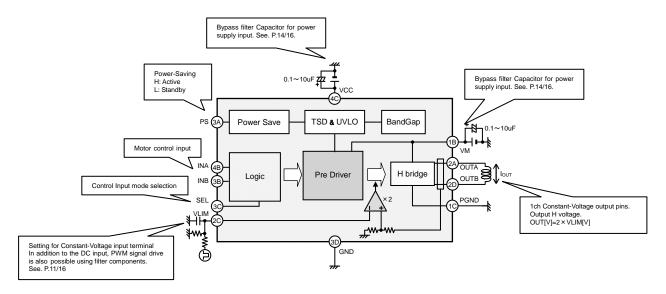


Fig.23 BD6886GUL, BD6369GUL Block Diagram, Application Circuit Diagram

	1	2	3	4
Α	N.C.	OUTA	PS	N.C.
В	VM	INDEX POST	INB	INA
С	PGND	VLIM	SEL	VCC
D	N.C.	OUTB	GND	N.C.

Fig.24 BD6886GUL, BD6369GUL Pin Arrangement (Top View)

BD6886GUL, BD6369GUL Pin Function Table

No.	Pin Name	Function	No.	Pin Name	Function
	Ivairie			Ivallic	
1A	N.C.	N.C.	1C	PGND	Motor ground pin
2A	OUTA	H-bridge output pin A	2C	VLIM	Output high-level voltage setting pin
3A	PS	Power-saving pin	3C	SEL	Control input mode selection pin
4A	N.C.	N.C.	4C	VCC	Power supply pin
1B	VM	Motor power supply pin	1D	N.C.	N.C.
2B			2D	OUTB	H-bridge output pin B
3B	INB	Control input pin B	3D	GND	Ground pin
4B	INA	Control input pin A	4D	N.C.	N.C.

Function Explanation

1) Power-saving function (all series)

When the L voltage is applied the PS pin, the IC's inside circuit stop, and when 0V applied, the circuit current became 0µA(Typ.), especially.

When the IC drive, serial input while the PS pin applied H voltage. (See the electrical characteristics; P.3, 4, 5/16)

2) Control Input Pin

(I) IN pin (BD6883GUL, BH6453GUL)

The IN pin is used to program and control the motor drive modes.

(See the electrical characteristics; P3, 4/16, and the I/O Truth Table; P12/16)

(II) INA, INB, SEL pins (BD6886GUL, BD6369GUL)

The INA and INB are used to program and control the motor drive modes.

When the L voltage is applied to the SEL pin, the I/O logic can be set to EN (Enable)/IN mode, and when the H voltage is applied to the one, the I/O logic can be set to IN/IN mode. (See the electrical characteristics; P5/16, and the I/O Truth Table; P12/16)

3) H-bridge and Half-bridge on the output stage (ALL series)

Specify maximum current applied to the H-bridge and Half-bridge within the operating range, in consideration of power dissipation. (See the Operating Conditions; P.2/16)

4) Drive system of Linear Constant-Voltage H-bridge (BD6883GUL, BD6886GUL, and BD6369GUL)

To set up the output H voltage, when the voltage input to the VLIM pin, the output H voltage is two times as high as the voltage.

(I) BD6883GUL The output H voltage VOH [V] = $2.0 \times \text{VLIM}$ [V] (When VLIM [V] > $\frac{\text{VCC}[V]}{2}$, Output H voltage is about VCC voltage)①

(II) BD6886GUL, BD6369GUL

The output H voltage VOH [V] = $2.0 \times \text{VLIM}$ [V] (When VLIM [V] > $\frac{\text{VM} [V]}{2}$, Output H voltage is about VM voltage)@

For example, the output voltage is $2.0V \pm 5\%$, if 1.0V is applied to the VLIM pin.

If the VLIM pin is shorted to the VM pin (or the same voltage level as the VM is applied), you can be used as a Full-ON Drive H-bridge.

5) Drive system of Linear Constant-Current H-bridge (BH6453GUL)

To detect the output current and the output current settings

The BH6453GUL built in resistor for output current detect. The output current is kept constant by comparing it with the CLIM voltage. In addition, impress a highly accurate voltage form the outside of IC to the CLIM terminal, when you do the output current setting accuracy or more good.

Output current
$$I_{SINK}[A] = \frac{CLIM[V]}{2 \times 2(Typ)[\Omega]}$$

If the CLIM pin applied 0.8V, Output current is 200mA±10%.

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7) Setting of PWM signal input VLIM and CLIM terminals (all series)

It is also possible to compose filters outside the IC, change an input voltage for output voltage and output current setting terminals such as VLIM and CLIM terminals by the DUTY control using an PWM signal, etc., and use them as set values for control. In this case, however, ensure the smoothing of the signals, heeding the constant number of the low-pass filter as stated below. A cutoff frequency F_C (-3dB attenuation frequency) of the low-pass filter in Fig25 is calculated by the formula mentioned below.

Cutoff frequency
$$F_C[Hz] = \frac{1}{2 \pi C_{IN} (R_{INA}//R_{INB})}$$
 [Hz]

Set the cutoff frequency F_C at 1/100 or below of the PWM frequency F_{PWM}.

For example, if the cutoff frequency F_C is set at 1/100 of F_{PWM} when the PWM frequency F_{PWM} =50[kHz], according to the formula above:

Cutoff frequency
$$F_C[Hz] = \frac{1}{2\pi C_{IN} (R_{INA}//R_{INB})} = \frac{1}{100} \times F_{PWM} = \frac{50 \times 10^3}{100} [Hz]$$
§

When $C_{IN}=0.1[\mu F]$, according to the formula above

$$R_{INA}//R_{INB}=3.2[k\Omega]$$
(6)

ON time

Where, an effective value of PWM signal as a DC current, according to crest values V_{MAX} and ON DUTY [%]=ON time+OFF time is as follows:

$$V_{PWM}[V] = V_{MAX}[V] \times ON DUTY[\%]$$

An actual voltage V_{LIM} input to terminals that specify output current and voltages, such as VLIM and CLIM terminals is as follows according to resistance potential division of R_{INA} and R_{INB} :

$$V_{\text{LIM}}[V] = \frac{R_{\text{INB}}}{R_{\text{INA}} + R_{\text{INB}}} \times V_{\text{PWM}}[V] \qquad_{\$}$$

For example, when an PWM signal with crest values $V_{MAX}=3[V]$ and DUTY [%]=5[%] is input, a V_{LIM} value according to the formula above is:

$$V_{\text{LIM}}[V] = \frac{R_{\text{INB}}}{R_{\text{INA}} + R_{\text{INB}}} \times 3[V] \times 50[\%] \qquad \dots$$

(I) BD6883GUL, BD6886GUL, and BD6369GUL

Where, to specify an output voltage VOH=2[V], a value VLIM=1.0[V] according to the formula in the previous page. And then, according to the formula above, VLIM=1.0[V].

$$VLIM=1.0[V]=V_{LIM}=\frac{R_{INB}}{R_{INA}+R_{INB}} \times 3[V] \times 50[\%]$$

Therefore, R_{INA}=0.5R_{INB}

According to 6 and 10, R_{INA} =4.8k Ω , R_{INB} =9.6k Ω .

(II) BH6453GUL

Where, to specify an output current $I_{SINK}=100[mA]$, the following formula is derived according to the formula in the previous page 3, CLIM=0.4[V], and according to the formula above 9:

$$\begin{array}{c} \text{CLIM=0.4[V]=V_{LIM}=} \ \ \, \frac{R_{INB}}{R_{INA}+R_{INB}} \ \ \, \times \, 3[V] \times \, 50[\%] \\ \\ R_{INA}=2.75R_{INB} & \dots \dots & \textcircled{1} \\ \end{array}$$

According to 6 and 1: $R_{INA}=11.9k\Omega$, $R_{INB}=4.3k\Omega$

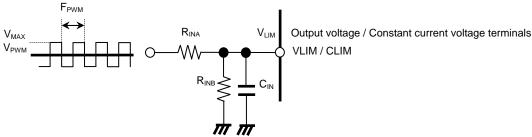


Fig.25 Example PWM signal input

●I/O Truth Table

BD6883GUL I/O Truth Table

MODE	INF	TU	OUTPUT	OUTPUT MODE	
MODE	PS	IN	OUT	OUTPUT MODE	
		L	L	Sink	
-	П	Н	Н	Source	
-	L	Χ	Z**7	Standby	

L: Low, H: High, X: Don't care, Z: Hi impedance

Sink is a direction of current flowing into the driver, and Source is a direction of current flowing out the driver.

When it is sink, which drive FULL ON.

BH6453GUL I/O Truth Table

MODE	INF	PUT	OUTPUT	OUTDUT MODE
	PS		OUT	OUTPUT MODE
		Н	L	Sink
-	Н	L	Н	Source
-	L	Х	Z	Standby

L: Low, H: High, X: Don't care, Z: Hi impedance

Sink is a direction of current flowing into the driver, and Source is a direction of current flowing out the driver.

When it is source, which drive FULL ON.

BD6886GUL, BD6369GUL I/O Truth Table

MODE		INF	PUT		OUT	PUT	OUTPUT MODE	
IVIODE	PS	SEL	INA	INB	OUTA	OUTB	OUTPUT MODE	
			L	Χ	Z* ⁷	Z* ⁷	Standby	
EN/IN		L	Н	L	Н	L	Forward rotation	
			Н	Н	L	Η	Reverse rotation	
	Н		L	L	L	Ш	Brake	
IN/IN		Н	L	Н	L	Н	Reverse rotation	
IIN/IIN		П	Н	L	Н	L	Forward rotation	
			Н	Н	Z*8	Z*8	Standby	
-	L	Χ	Χ	X	Z*8	Z*8	Standby	

L: Low, H: High, X: Don't care, Z: Hi impedance

^{**&}lt;sup>7</sup>Z at the Constant-Voltage driver output L voltage for connect feedback resistance (20kΩ Typ.) for output H voltage setting between OUT pin and GND. But output Power MOS is OFF condition.

At forward rotation, current flows from OUTA to OUTB. At reverse rotation, current flows from OUTB to OUTA.

^{**8}Z at the Constant-Voltage driver output L voltage for connect feedback resistance (20kΩ Typ.) for output H voltage setting between OUT pin and GND. But output Power MOS is OFF condition.

●I/O Circuit Diagram

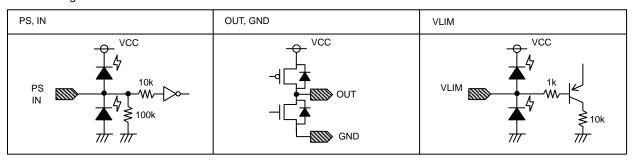


Fig.26 BD6883GUL I/O Circuit Diagram (Resistance values are typical ones.)

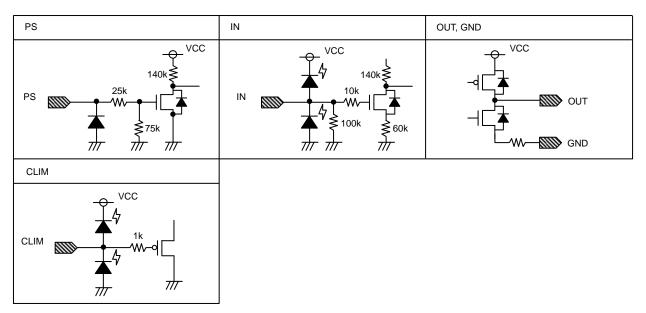


Fig.27 BH6453GUL I/O Circuit Diagram (Resistance values are typical ones.)

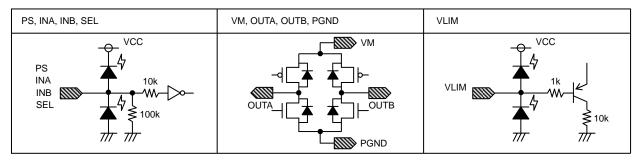


Fig.28 BD6886GUL, BD6369GUL I/O Circuit Diagram (Resistance values are typical ones.)

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Operation Notes

Absolute maximum ratings

Use of the IC in excess of absolute maximum ratings, such as the applied voltage (VCC, VM) or operating temperature range (Topr), may result in IC damage. Assumptions should not be made regarding the state of the IC (short mode or open mode) when such damage is suffered. A physical safety measure, such as a fuse, should be implemented when using the IC at times where the absolute maximum ratings may be exceeded.

2) Storage temperature range (Tstg)

As long as the IC is kept within this range, there should be no problems in the IC's performance. Conversely, extreme temperature changes may result in poor IC performance, even if the changes are within the above range.

3) Power supply and wiring

Be sure to connect the power terminals outside the IC. Do not leave them open. Because a return current is generated by a counter electromotive force of the motor, take necessary measures such as putting a Capacitor between the power source and the ground as a passageway for the regenerative current. Be sure to connect a Capacitor of proper capacitance $(0.1\mu\text{F}\ to\ 10\mu\text{F})$ between the power source and the ground at the foot of the IC, and ensure that there is no problem in properties of electrolytic Capacitors such as decrease in capacitance at low temperatures. When the connected power source does not have enough current absorbing capability, there is a possibility that the voltage of the power source line increases by the regenerative current an exceeds the absolute maximum rating of this product and the peripheral circuits.

Therefore, be sure to take physical safety measures such as putting a zener diode for a voltage clamp between the power source an the ground.

4) Ground terminal and wiring

The potential at GND terminals should be made the lowest under any operating conditions. Ensure that there are no terminals where the potentials are below the potential at GND terminals, including the transient phenomena. The motor ground terminals PGND, and the small signal ground terminal GND are not interconnected with one another inside the IC. It is recommended that you should isolate the large-current RNF pattern and PGND pattern from the small-signal GND pattern, and should establish a one-point grounding at a reference point of the set, to avoid fluctuation of small-signal GND voltages caused by voltage changes due to pattern wire resistances and large currents. Also prevent the voltage variation of the ground wiring patterns of external components. Use short and thick power source and ground wirings to ensure low impedance.

5) Thermal design

Use a proper thermal design that allows for a sufficient margin of the power dissipation (Pd) at actual operating conditions.

6) Pin short and wrong direction assembly of the device.

Use caution when positioning the IC for mounting on printed circuit boards. The IC may be damaged if there is any connection error or if positive and ground power supply terminals are reversed. The IC may also be damaged if pins are shorted together or are shorted to other circuit's power lines.

7) Avoiding strong magnetic field

Malfunction may occur if the IC is used around a strong magnetic field.

8) ASC

Ensure that the output transistors of the motor driver are not driven under excess conditions of the absolute maximum ratings and ASO.

9) TSD (Thermal Shut Down) circuit

If the junction temperature (Tjmax) reaches 175°C (but the BH6453GUL is 150°C), the TSD circuit will operate, and the coil output circuit of the motor will open. There is a temperature hysterics of approximately 25°C (but the BH6453GUL is 20°C). The TSD circuit is designed only to shut off the IC in order to prevent runaway thermal operation. It is not designed to protect the IC or guarantee its operation. The performance of the IC's characteristics is not guaranteed and it is recommended that the device is replaced after the TSD is activated.

10) Testing an application board

When testing the IC on an application board, connecting a Capacitor to a pin with low impedance subjects the IC to stress. Always discharge Capacitors after each process or step. Always turn the IC's power supply off before connecting it to, or removing it from a jig or fixture, during the inspection process. Ground the IC during assembly steps as an antistatic measure. Use similar precaution when transporting and storing the IC.

11) Regarding the input pin of the IC

This monolithic IC contains P^+ isolation and P substrate layers between adjacent elements to keep them isolated. P-N junctions are formed at the intersection of these P layers with the N layers of other elements, creating a parasitic diode or transistor. For example, the relation between each potential is as follows:

When GND > Pin A, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic diode and transistor.

Parasitic elements can occur inevitably in the structure of the IC. The operation of parasitic elements can result in mutual interference among circuits, operational faults, or physical damage. Accordingly, methods by which parasitic elements operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin, should not be used.

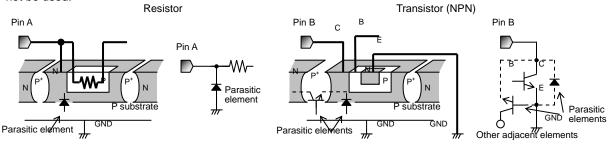
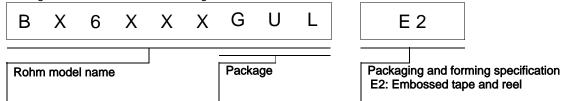


Fig.29 Example of Simple IC Architecture





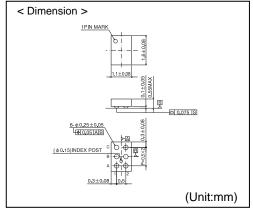
 6883 : Constant voltage 0.5ch
 GUL : VCSP50L1 (BD6883)

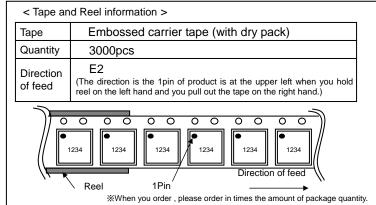
 6453 : Constant current 0.5ch
 GUL : VCSP50L1 (BH6453)

 6886 : Constant voltage 1ch
 GUL : VCSP50L2 (BD6886)

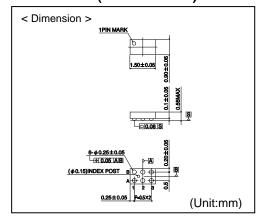
 6369 : Constant voltage 1ch
 GUL : VCSP50L2 (BD6369)

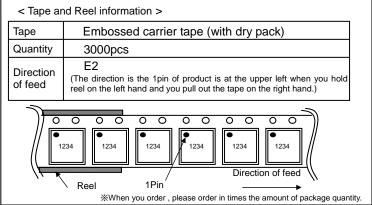
VCSP50L1 (BD6883GUL)



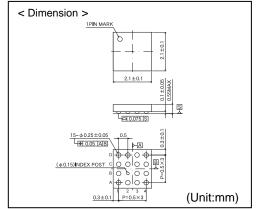


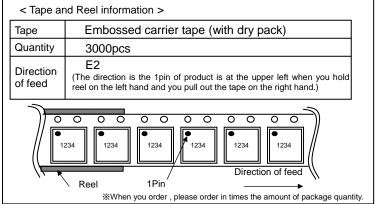
VCSP50L1 (BH6453GUL)





VCSP50L2 (BD6886GUL, BD6369GUL)





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JÁPA	AN '	USA	EU	CHINA
CLASSⅢ		CLACCIII	CLASS II b	CLASSIII
CLAS	SIV	CLASSⅢ	CLASSⅢ	CLASSIII

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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

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 - [d] the Products are exposed to high Electrostatic
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